

Substitute for Form 1449 A & B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				<i>Complete if Known</i>	
				Application Number	Unknown
				Confirmation Number	Unknown
				Filing Date	September 18, 2003
				First Named Inventor	Katsumi ABE
				Art Unit	Unknown
Examiner Name	Unknown				
Sheet	1	of	1	Attorney Docket Number	Q75817

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ² (if known)		
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FOREIGN PATENT DOCUMENTS							
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/TP/		JP	11-194320	A	07/21/1999		
/TP/		JP	11-194316	A	07/21/1999		

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/TP/		T. Nakamura et al., "Low-Temperature Poly-Si TFT-LCD with Integrated Analog Circuit", Asia Display/IDW 01 Proceedings, October 16, 2001, pp. 1603-1606 with Abstract.	
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